

Customer No.: 31561  
Docket No.: 12009-US-PA  
Application No.: 10/605,782

**In The Claim**

Claim 1 (currently amended) A method for forming a nitrided tunnel oxide layer, comprising:

performing an in-situ steam generation (ISSG) process to form a silicon oxide layer as a tunnel oxide layer on a semiconductor substrate;

performing a plasma nitridation process to introduce nitrogen atoms into the silicon oxide layer; and

performing a thermal drive-in process to diffuse the introduced nitrogen atoms across the silicon oxide layer, wherein the thermal drive-in process is conducted under 850 to 1100°C for 30 seconds to 1 hour.

Claim 2 (canceled)

Claim 3 (original) The method of claim 1, wherein the plasma nitridation process utilizes N<sub>2</sub> plasma.

Claim 4 (original) The method of claim 1, wherein the plasma nitridation process is conducted under a temperature lower than 400°C.

Claim 5 (original) The method of claim 1, wherein the thermal drive-in process comprises a furnace annealing process or a rapid thermal annealing process.

Claims 6-12 (canceled)

Claim 13 (previously presented) A method for forming a nitrided tunnel oxide layer, comprising:

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performing an in-situ steam generation (ISSG) process to form a silicon oxide layer as a tunnel oxide layer on a semiconductor substrate;

performing a N<sub>2</sub> plasma nitridation process to introduce nitrogen atoms into the silicon oxide layer; and

performing a thermal drive-in process to diffuse the introduced nitrogen atoms across the silicon oxide layer, wherein the thermal drive-in process is conducted under 850 to 1100°C for 30 seconds to 1 hour.

Claim 14 (previously presented) The method of claim 13, wherein the N<sub>2</sub> plasma nitridation process is conducted under a temperature lower than 400°C.

Claim 15 (previously presented) The method of claim 13, wherein the thermal drive-in process comprises a furnace annealing process or a rapid thermal annealing process.

Claim 16 (canceled)